

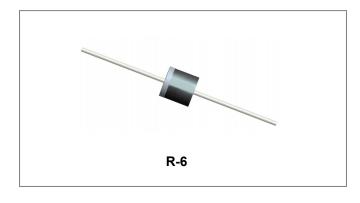
### Technical Data Data Sheet N0549, Rev. C



# 6A05 THRU 6A10

GENERAL PURPOSE SILICON RECTIFIER

Reverse Voltage - 50 to 1000 Volts Forward Current - 6.0 Amperes



### Features

- The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- Construction utilizes void-free molded plastic technique
- Low reverse leakage
- High forward surge current capability
- High temperature soldering guaranteed: 250°C /10 seconds,0.375"(9.5mm) lead length, 5 lbs. (2.3kg) tension
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

### **Mechanical Data**

- Case: R-6 molded plastic
- Terminals: Plated axial leads, solderable per MIL-STD-202, Method 208
- Polarity: Color band denotes cathode end
- Mounting Position: Any
- Weight: 2.1 grams

# Maximum Ratings and Electrical Characteristics @T<sub>A</sub>=25°C unless otherwise specified

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

Type Number	Symbol	6A05	6A1	6A2	6A4	6A6	6A8	6A10	Units
Maximum repetitive peak reverse voltage Maximum DC blocking voltage	V <sub>RRM</sub> V <sub>DC</sub>	50	100	200	400	600	800	1000	V
Maximum RMS voltage	VRMS	35	70	140	280	420	560	700	V
Maximum average forward rectified current 0.375"(9.5mm) lead length at $@T_A = 60^{\circ}C$	I <sub>(AV)</sub>	6.0				А			
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	IFSM	400			A				
Maximum instantaneous forward voltage at 6.0A	VF	0.95		V					
Maximum DC reverse current $@T_A = 25^{\circ}C$ At Rated DC Blocking Voltage $@T_A = 100^{\circ}C$	I <sub>R</sub>	10.0 400		μA					
Typical Junction Capacitance (Note 1)	CJ	C <sub>J</sub> 150			pF				
Typical Thermal Resistance (Note 2)	R <sub>0JA</sub>				10.0				°C/W
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>			-	65 to +1	75			°C

Note: 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2. Thermal resistance from junction to ambient at 0.375"(9.5mm)lead length, P.C.B. mounted

- China Germany Korea Singapore United States •
- http://www.smc-diodes.com sales@ smc-diodes.com •

# **Circuit Diagram**



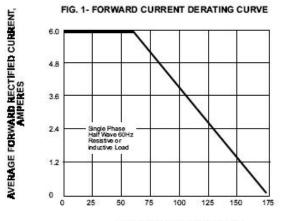


# 6A05-6A10

### Technical Data Data Sheet N0549, Rev. C

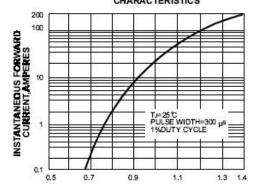
# RoHS 🗭

### **Ratings and Characteristics Curves**



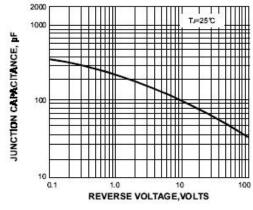
AMBIENT TEMPERATURE, °C

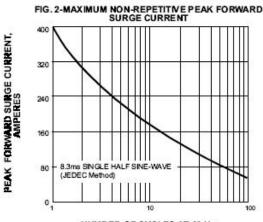




INSTANTANEOUS FORWARD VOLEAGE, VOLTS







NUMBER OF CYCLES AT 60 Hz

FIG. 4-TYPICAL REVERSE CHARACTERISTICS

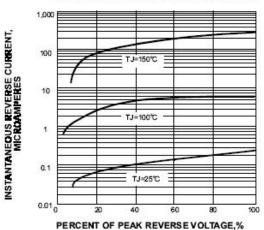
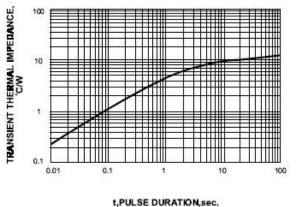


FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE



China - Germany - Korea - Singapore - United States http://www.smc-diodes.com - sales@ smc-diodes.com -

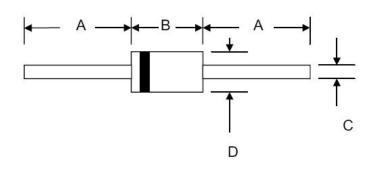


# 6A05-6A10



### Technical Data Data Sheet N0549, Rev. C

# **Mechanical Dimensions R-6**



OVMDOL	Millim	neters	Inches			
SYMBOL	Min.	Max.	Min.	Max.		
А	24.0	-	0.940	-		
В	8.60	9.10	0.340	0.360		
С	1.2	1.3	0.048	0.052		
D	8.60	9.10	0.340	0.360		

# **Ordering Information**

Device	Package	Shipping
6A05-6A10	R-6 (Pb-Free)	500pcs / Tape

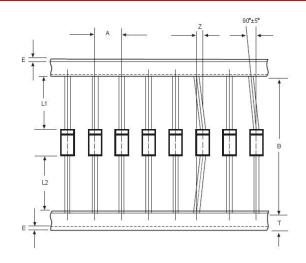
For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

# Marking Diagram



6A05 = Type Number

## **Carrier Tape Specification R-6**



SYMBOL	Millimeters			
	Min.	Max.		
A	9.50	10.50		
В	50.9	53.9		
Z	-	1.20		
Т	5.60	6.40		
E	-	0.80		
IL1-L2I	-	1.0		



### Technical Data Data Sheet N0549, Rev. C



### DISCLAIMER:

1- The information given herein, including the specifications and dimensions, is subject to change without prior notice to improve product characteristics. Before ordering, purchasers are advised to contact the SMC - Sangdest Microelectronics (Nanjing) Co., Ltd sales department for the latest version of the datasheet(s).

2- In cases where extremely high reliability is required (such as use in nuclear power control, aerospace and aviation, traffic equipment, medical equipment, and safety equipment), safety should be ensured by using semiconductor devices that feature assured safety or by means of users' fail-safe precautions or other arrangement.

3- In no event shall SMC - Sangdest Microelectronics (Nanjing) Co., Ltd be liable for any damages that may result from an accident or any other cause during operation of the user's units according to the datasheet(s). SMC - Sangdest Microelectronics (Nanjing) Co., Ltd assumes no responsibility for any intellectual property claims or any other problems that may result from applications of information, products or circuits described in the datasheets.

4- In no event shall SMC - Sangdest Microelectronics (Nanjing) Co., Ltd be liable for any failure in a semiconductor device or any secondary damage resulting from use at a value exceeding the absolute maximum rating.

5- No license is granted by the datasheet(s) under any patents or other rights of any third party or SMC - Sangdest Microelectronics (Nanjing) Co., Ltd.

6- The datasheet(s) may not be reproduced or duplicated, in any form, in whole or part, without the expressed written permission of SMC - Sangdest Microelectronics (Nanjing) Co., Ltd.

7- The products (technologies) described in the datasheet(s) are not to be provided to any party whose purpose in their application will hinder maintenance of international peace and safety nor are they to be applied to that purpose by their direct purchasers or any third party. When exporting these products (technologies), the necessary procedures are to be taken in accordance with related laws and regulations..

http://www.smc-diodes.com - sales@ smc-diodes.com •

# **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Diodes - General Purpose, Power, Switching category:

Click to view products by Sangdest manufacturer:

Other Similar products are found below :

MCL4151-TR3 MMBD3004S-13-F RD0306T-H RD0506LS-SB-1H RGP30G-E373 DSE010-TR-E BAQ333-TR BAQ335-TR BAQ33-GS18 BAS1602VH6327XT BAV17-TR BAV19-TR BAV301-TR BAW27-TAP HSC285TRF-E NSVBAV23CLT1G NTE525 1SS181-TP 1SS184-TP 1SS193,LF 1SS193-TP 1SS400CST2RA SBAV99LT3G SDAA13 LL4448-GS18 SHN2D02FUTW1T1G LS4150GS18 LS4151GS08 SMMBD7000LT3G FC903-TR-E 1N4449 1N4934-E3/73 1SS226-TP APT100DL60HJ RFUH20TB3S RGP30G-E354 RGP30M-E3/73 D291S45T MCL4151-TR BAS 16-02V H6327 BAS 21U E6327 BAS 28 E6327 BAS33-TAP BAS 70-02V H6327 BAV300-TR BAV303-TR3 BAW27-TR BAW56DWQ-7-F BAW56M3T5G BAW75-TAP